

M/A-COM Products

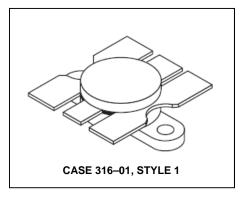
Released - Rev. 07.07

The RF Line NPN Silicon Power Transistor 100W, 30-200MHz, 28V

Designed primarily for wideband large–signal output amplifier stages in 30–200 MHz frequency range.

- Guaranteed performance at 150 MHz, 28 Vdc Output power = 100 W Minimum gain = 9.0 dB
- Built-in matching network for broadband operation
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Gold metallization system for high reliability
- High output saturation power ideally suited for 30 W carrier/120 W
- Peak AM amplifier service
- Guaranteed performance in broadband test fixture

Product Image



MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|------------------|-------------|---------------|
| Collector–Emitter Voltage | V _{CEO} | 35 | Vdc |
| Collector–Base Voltage | V _{CBO} | 65 | Vdc |
| Emitter–Base Voltage | V _{EBO} | 4.0 | Vdc |
| Collector Current — Continuous — Peak (10 seconds) | IC | 12 18 | Adc |
| Total Device Dissipation @ T _C = 25°C (1) Derate above 25°C | PD | 270 1.54 | Watts W/°C |
| Storage Temperature Range | T _{stg} | -65 to +150 | °C |

THERMAL CHARACTERISTICS

| Characteristic | | Symbol | Max | | Unit |
|--|--------|------------------|------|-----|------|
| Thermal Resistance, Junction to Case | | R _{θJC} | 0.65 | | °C/W |
| ELECTRICAL CHARACTERISTICS (T _C = 25°C unless otherwise noted.) | | | | | |
| Characteristic | Symbol | Min | Тур | Max | Unit |

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- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
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| Collector–Emitter Breakdown Voltage (I _C = 100 mAdc, I _B = 0) | V _{(BR)CEO} | 35 | _ | _ | Vdc |
|---|----------------------|-----|----|-----|------|
| Collector–Emitter Breakdown Voltage (I _C = 100 mAdc, V _{BE} = 0) | V _{(BR)CES} | 65 | _ | _ | Vdc |
| Collector–Base Breakdown Voltage (I _C = 100 mAdc, I _E = 0) | V _{(BR)CBO} | 65 | _ | _ | Vdc |
| Emitter–Base Breakdown Voltage (I _E = 10 mAdc, I _C = 0) | V _{(BR)EBO} | 4.0 | _ | _ | Vdc |
| Collector Cutoff Current (V _{CB} = 30 Vdc, I _E = 0) | Ісво | - | _ | 5.0 | mAdc |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain (I _C = 5.0 Adc, V _{CE} = 5.0 Vdc) | h _{FE} | 10 | 25 | 80 | _ |
| | | | | | |

NOTE:

(continued)

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

ELECTRICAL CHARACTERISTICS - continued (T_C = 25°C unless otherwise noted.)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|-----------------|--------------------------------|-----|-----|------|
| DYNAMIC CHARACTERISTICS | | | | | |
| Output Capacitance (V _{CB} = 28 Vdc, I _E = 0, f = 1.0 MHz) | C _{ob} | - | 150 | 175 | pF |
| FUNCTIONAL TESTS (Figure 2) | | • | | | |
| Common–Emitter Amplifier Power Gain (V _{CC} = 28 Vdc, P _{out} = 100 W, f = 150 MHz, I _C (Max) = 6.5 Adc) | G _{PE} | 9.0 | 10 | _ | dB |
| Collector Efficiency (V _{CC} = 28 Vdc, P _{out} = 100 W, f = 150 MHz, I _C (Max) = 6.5 Adc) | η | 55 | 60 | _ | % |
| Load Mismatch (V _{CC} = 28 Vdc, P _{out} = 100 W CW, f = 150 MHz, VSWR = 30:1 all phase angles) | Ψ | No Degradation in Output Power | | | |

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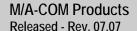
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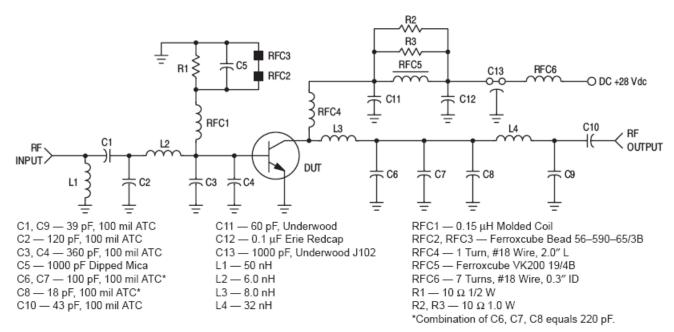
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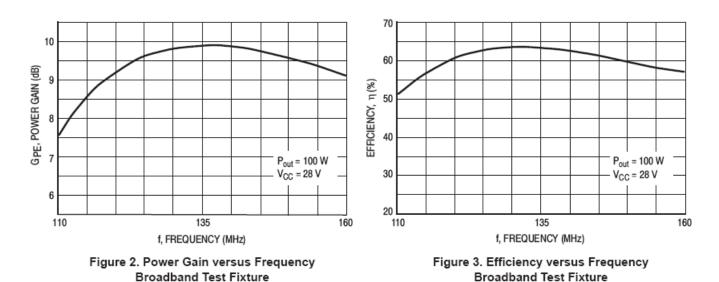


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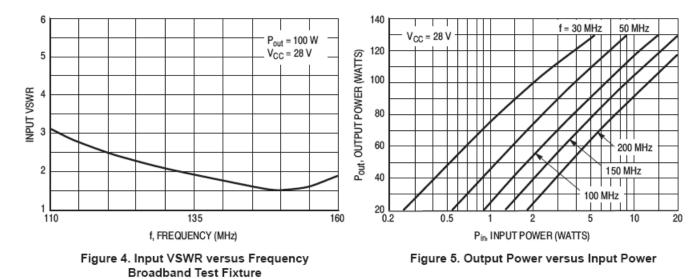


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TYPICAL PERFORMANCE CURVES

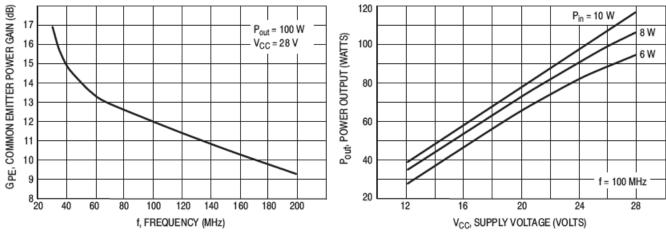


Figure 6. Power Gain versus Frequency

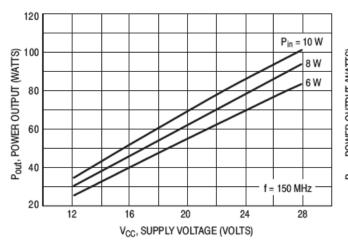
Figure 7. Power Output versus Supply Voltage

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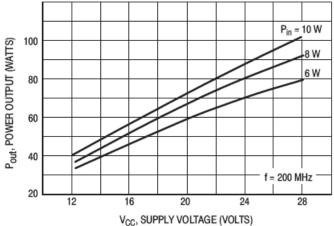
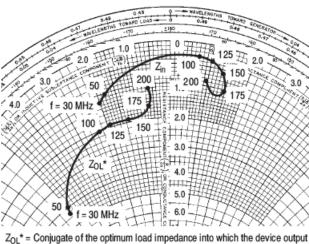


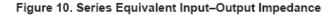
Figure 8. Power Output versus Supply Voltage





| V _{CC} = 28 V, P _{out} = 100 W | | | |
|--|-------------------------|---------------------------|--|
| f MHz | Z _{in} OHMS | Z _{OL} * OHMS | |
| 30 | 1.2 – j2.0 | 4.3 – j5.0 | |
| 50 | 1.0 - j1.8 | 4.0 - j4.9 | |
| 100 | 0.3 + j0.7 | 2.0 - j2.3 | |
| 125 | 0.3 + j1.0 | 1.9 – j1.9 | |
| 150 | 0.6 + j1.3 | 1.9 - j1.3 | |
| 175 | 1.0 + j1.5 | 1.6 – j0.6 | |
| 200 | 0.9 + j1.0 | 1.1 - j0.6 | |

Z_{OL}* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.



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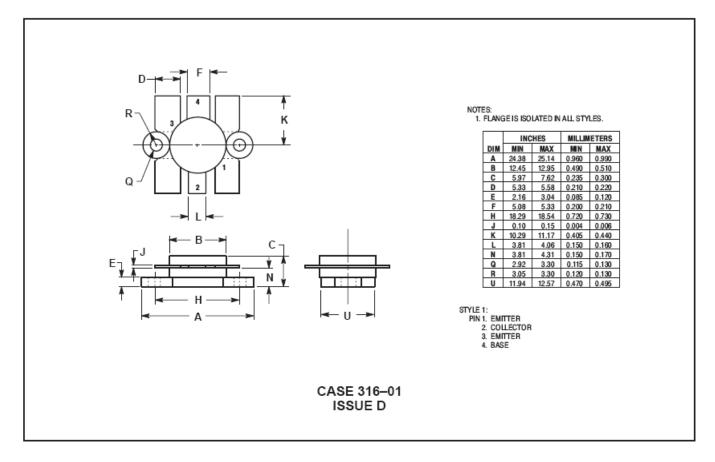
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PACKAGE DIMENSIONS



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